

# ECE 320 - Final pt 1 - Name \_\_\_\_\_

Semiconductors and Diodes. October 26, 2017

1a) What is the difference between n-type and p-type semiconductors?

n-type  $e^- \gg$  holes

p-type holes  $\gg e^-$

1b) For a semiconductor, does resistance go up or down as temperature goes up? Why?

~~up~~ R goes down.

As  $T \uparrow$ , the number of thermal  $e^-$  + holes goes up. More charge carriers means less resistance.

1c) Why does current flow from p to n for a diode but not n to p?

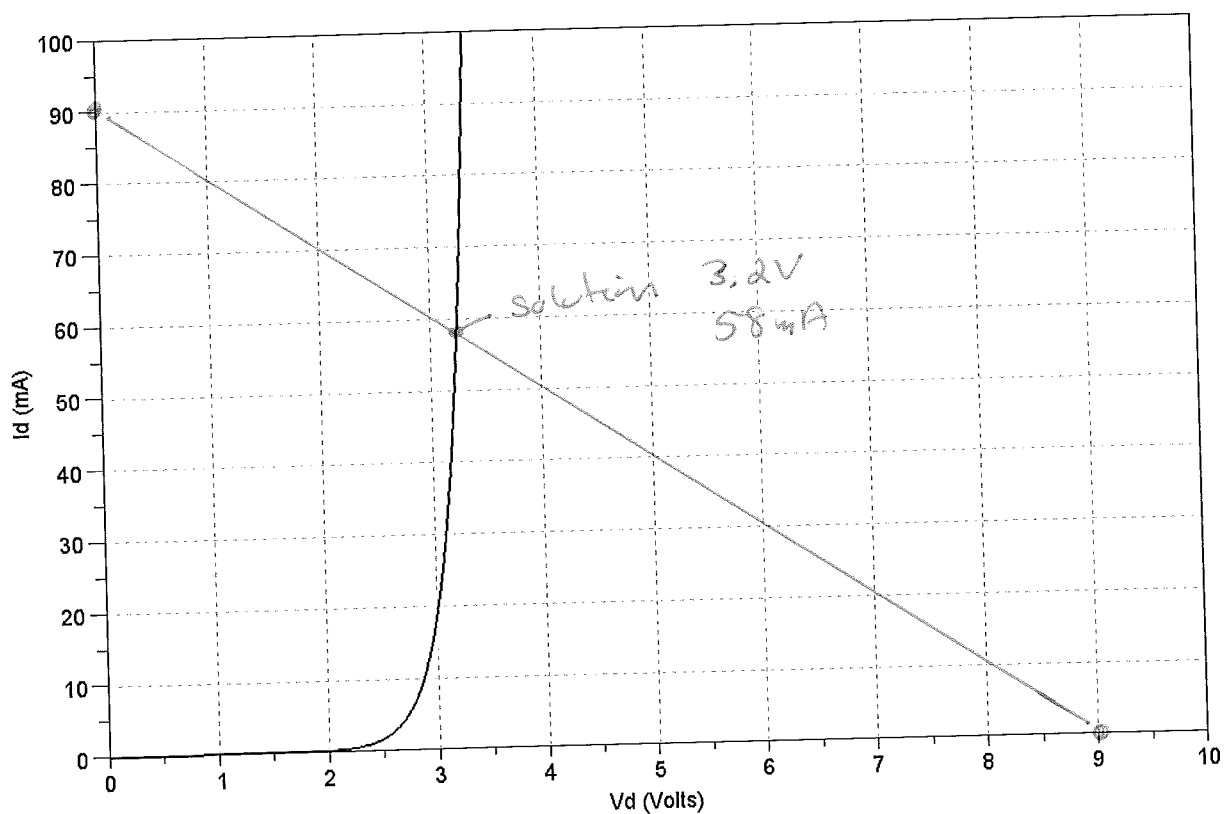
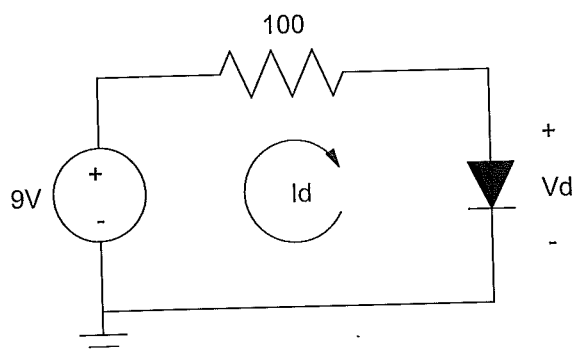
p to n uses majority carriers (low R)

n to p uses minority carriers (high R)

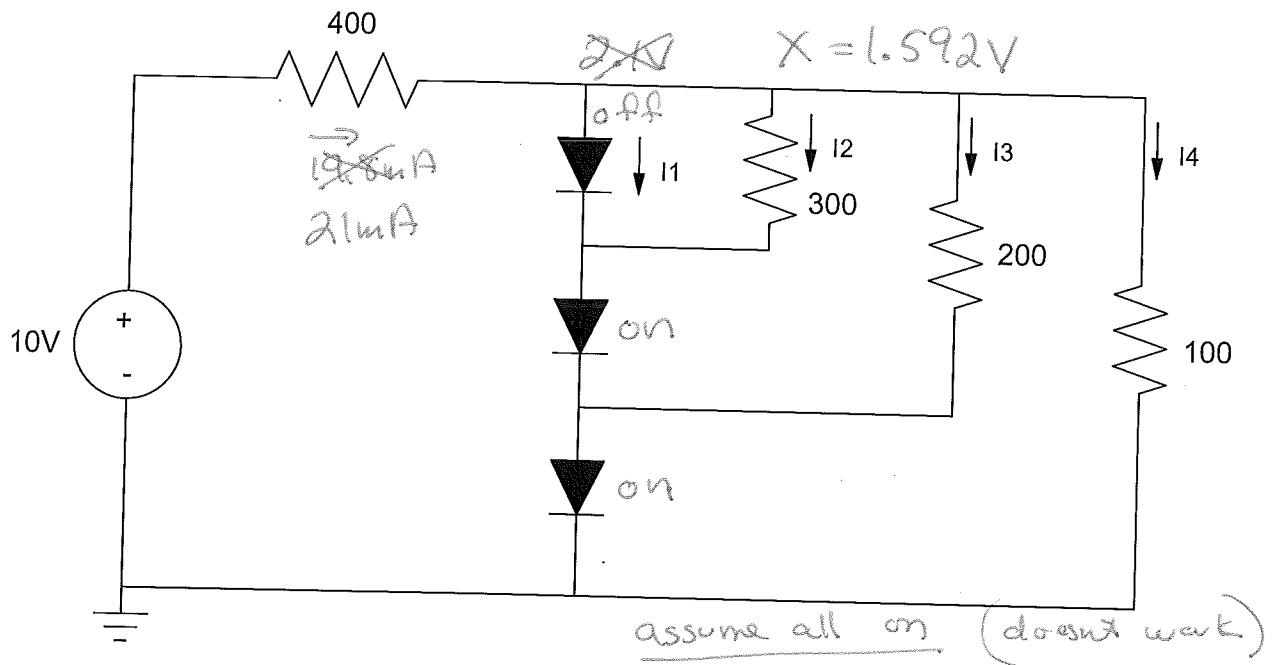
voltage p to n reduces the depletion zone to zero, allowing current flow  
n to p makes the depletion zone bigger

2) Load-Line pn-junction. The VI characteristics for a white LED is shown below. Draw the load line for the following circuit and determine  $V_c$  and  $I_d$

| Load Line ( $I_d$ vs $V_d$ ) | $V_d$ | $I_d$ |
|------------------------------|-------|-------|
| show on graph                | 3.2V  | 58mA  |



| I1   | I2    | I3     | I4      |
|------|-------|--------|---------|
| 0 mA | .6 mA | 4.5 mA | 15.9 mA |



assume D2 is off

$$\frac{X - .7}{200} + \frac{X}{100} + \frac{X - 10}{400} = 0$$

$$\left(\frac{1}{200} + \frac{1}{100} + \frac{1}{50}\right) X = \left(\frac{1}{200} + \frac{10}{50}\right)$$

$$X_2 = 1.628V \quad 71.41V$$

assume  $D2$  is on

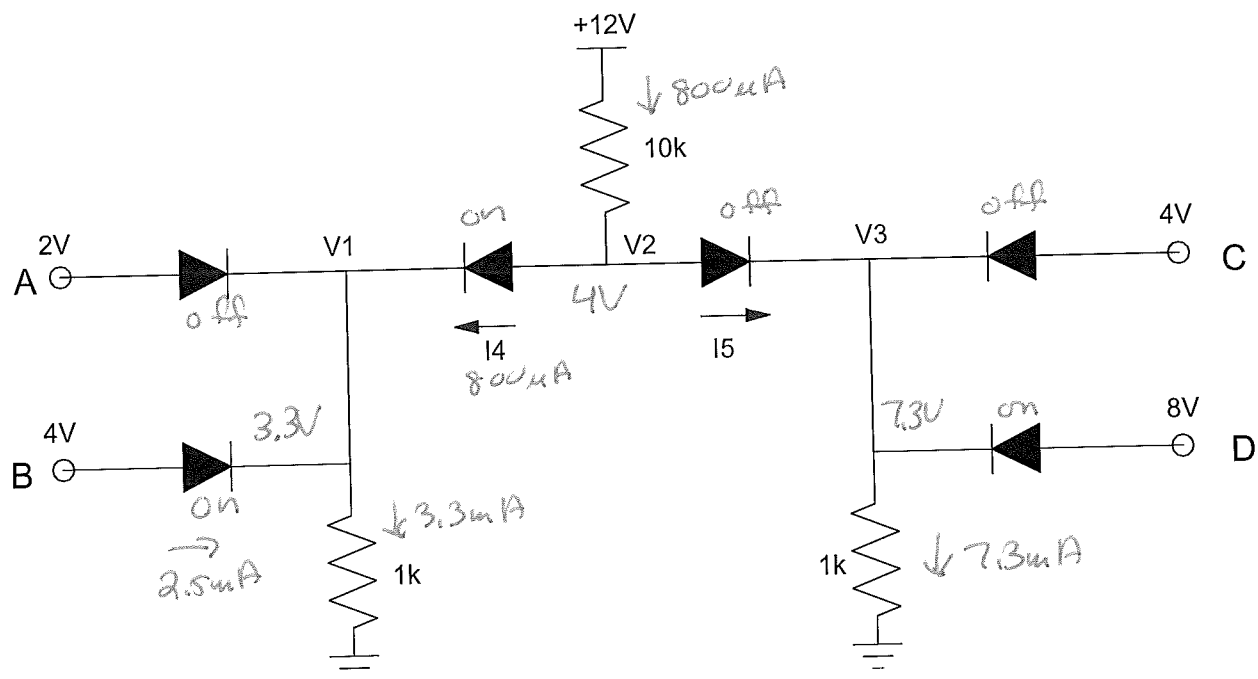
$$\frac{x-3}{100} + \frac{x-7}{200} + \frac{x-14}{300} + \frac{x-10}{400} = 0$$

$$\left(\frac{1}{1u} + \frac{1}{2u} + \frac{1}{3u} + \frac{1}{4u}\right)x = \left(\frac{12}{4u} + \frac{14}{3u} + \frac{17}{2u}\right)$$

$$x = 1.592V$$

4) Assume ideal silicon diodes with  $V_f = 0.7V$ . Determine the voltages and currents for the following max / min circuit.

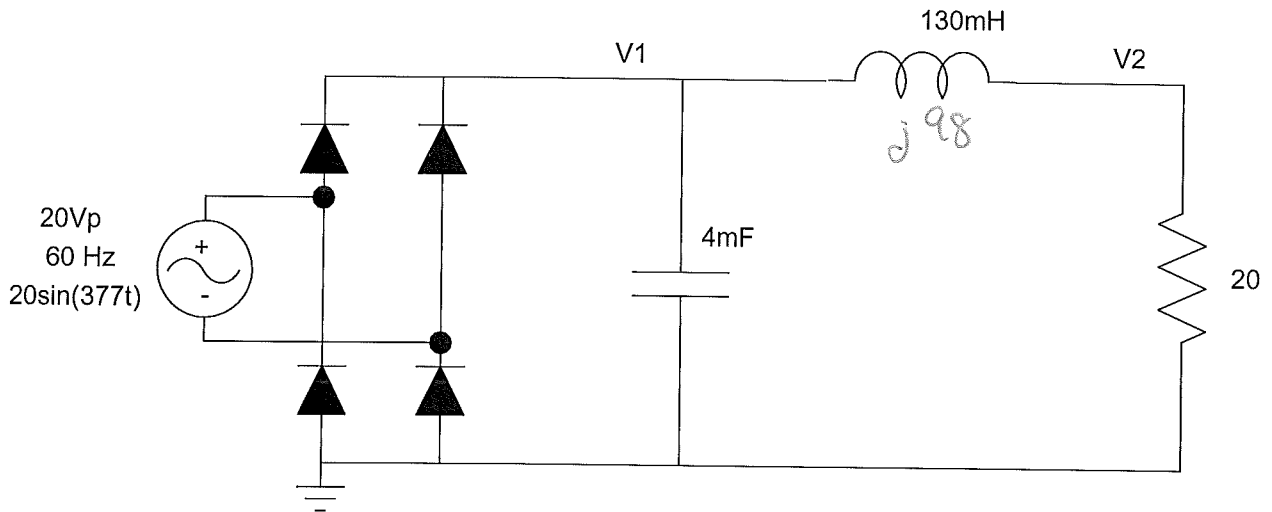
| V1   | V2 | V3   | I4         | I5 |
|------|----|------|------------|----|
| 3.3V | 4V | 7.3V | $800\mu A$ | ○  |



5 Determine the DC and AC voltages at V1 and V2 for the following AC to DC converter:

| V1      |                      | V2              |                     |
|---------|----------------------|-----------------|---------------------|
| max(V1) | V1pp<br>(AC)         | avg(V2)<br>(DC) | V2pp<br>(AC)        |
| 18.6V   | 1.938V <sub>pp</sub> | 17.6V           | 387mV <sub>pp</sub> |

$$18.6V - \frac{1}{2} V_{pp}$$



$$I = C \frac{dV}{dt}$$

$$V_{2pp} = \left( \frac{20}{20 + j98} \right) V_{1pp}$$

$$I \approx \frac{18.6V}{20\Omega} = 930mA$$

$$= 387 \angle -78^\circ$$

$$930mA = (4mF) \frac{dV}{V_{120}}$$

$$dV = 1.938V_{pp}$$

NR2L

Bonus! The US Energy Information Administration (EIA) estimates the cost of producing electricity by source for the year 2022. Rank the sources from least expensive (1) to most expensive (5)

| Clean Coal<br>30% Carbon Capture | Natural Gas | Nuclear     | Solar       | Wind       |
|----------------------------------|-------------|-------------|-------------|------------|
| 12c-19c<br>25                    | 5c-8c<br>2  | 9c-10c<br>4 | 5c-14c<br>3 | 4c-7c<br>1 |

6c-15c (no CO2)

15¢/kWh

14c-19c

5c-8c

9c-13c

10c

6c-25c

6c-14c

4c-8c

3c-6c

4c-8c NR2L

EIA  
2022

NR2L  
1997-2015

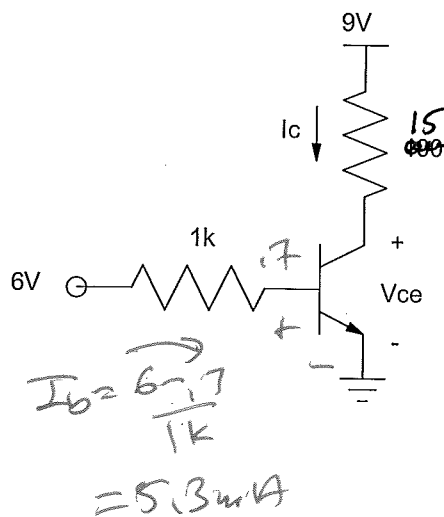
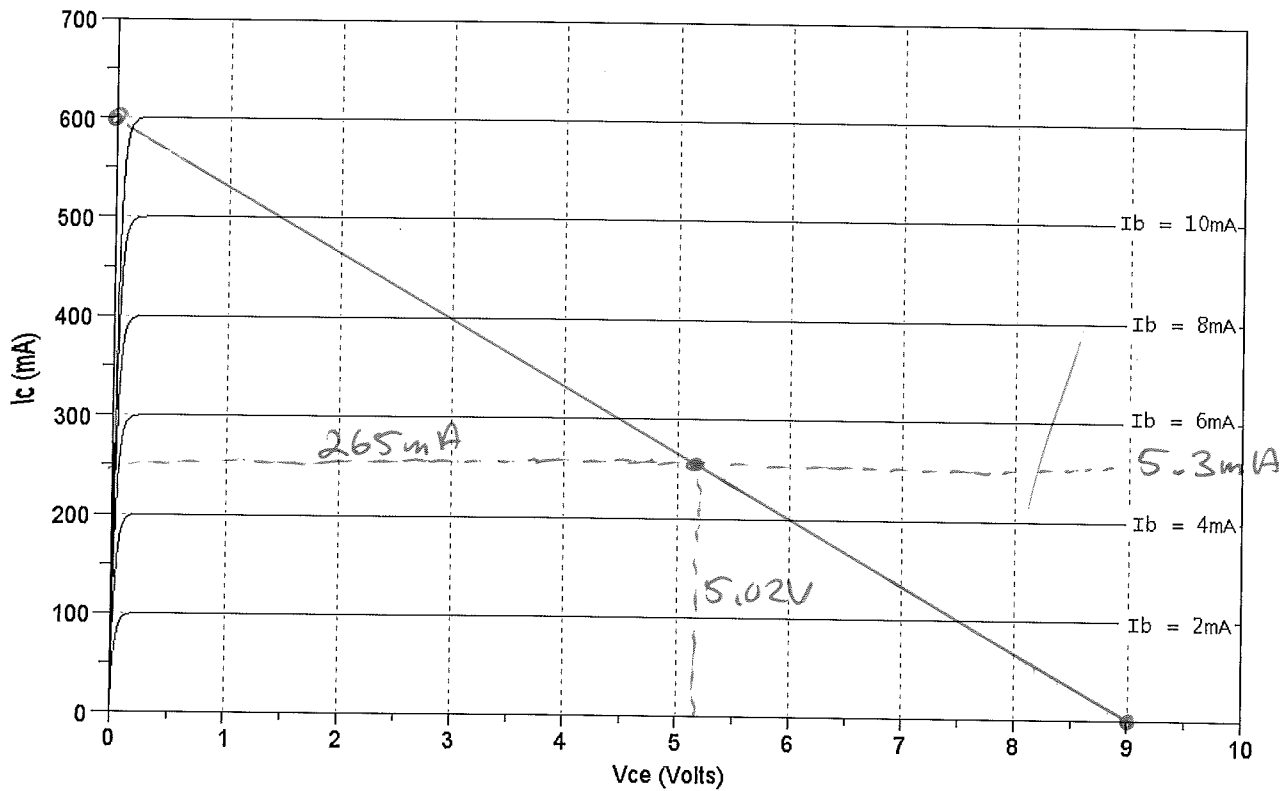


# ECE 320 - Final pt 2 - Name \_\_\_\_\_

Transistors and Op-Amp Circuits. October 27, 2017

## 1) Transistor Load Line

| Load Line     | Current Gain<br>Beta | $V_{ce}$ | $I_c = I_e$ |
|---------------|----------------------|----------|-------------|
| Show on Graph | 50                   | 5.02V    | 265mA       |



2) A transistor allows a 0V / 5V digital input to turn on and off a white LED at 100mA.

Input:

- 0V / 5V binary signal capable of 10mA

Output:

- 3W White LED.  $V_f = 3V @ 1A$ .

Relationship:

- When the input is 0V, 0mA flows through the LED
- When the input is 5V, 100mA flows through the LED.

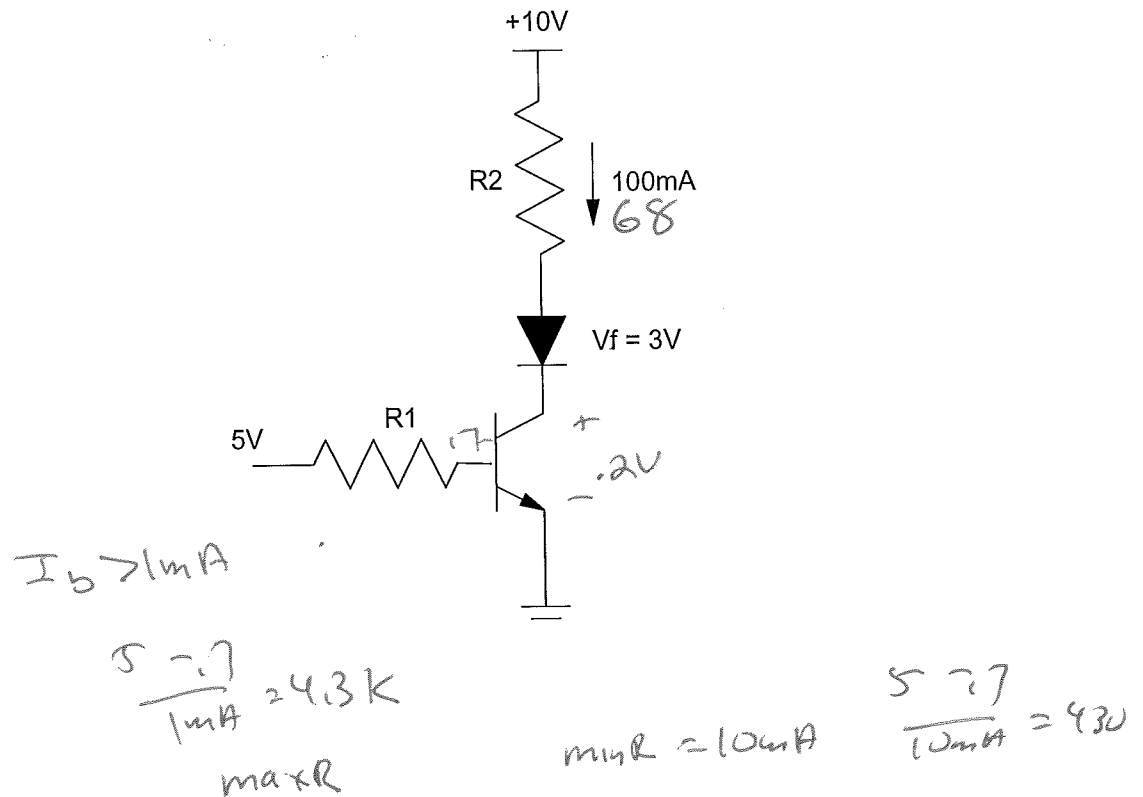
Find the allowable range of R1 and the required value for R2.

| min value of R1 | max value of R1 | R2 |
|-----------------|-----------------|----|
| 4.3k $\Omega$   | 430             | 68 |

← swap

Assume a transistor with the following characteristics (3904)

- $V_{be} = 0.7V$
- $V_{ce(sat)} = 0.2V$
- $\beta = 100$

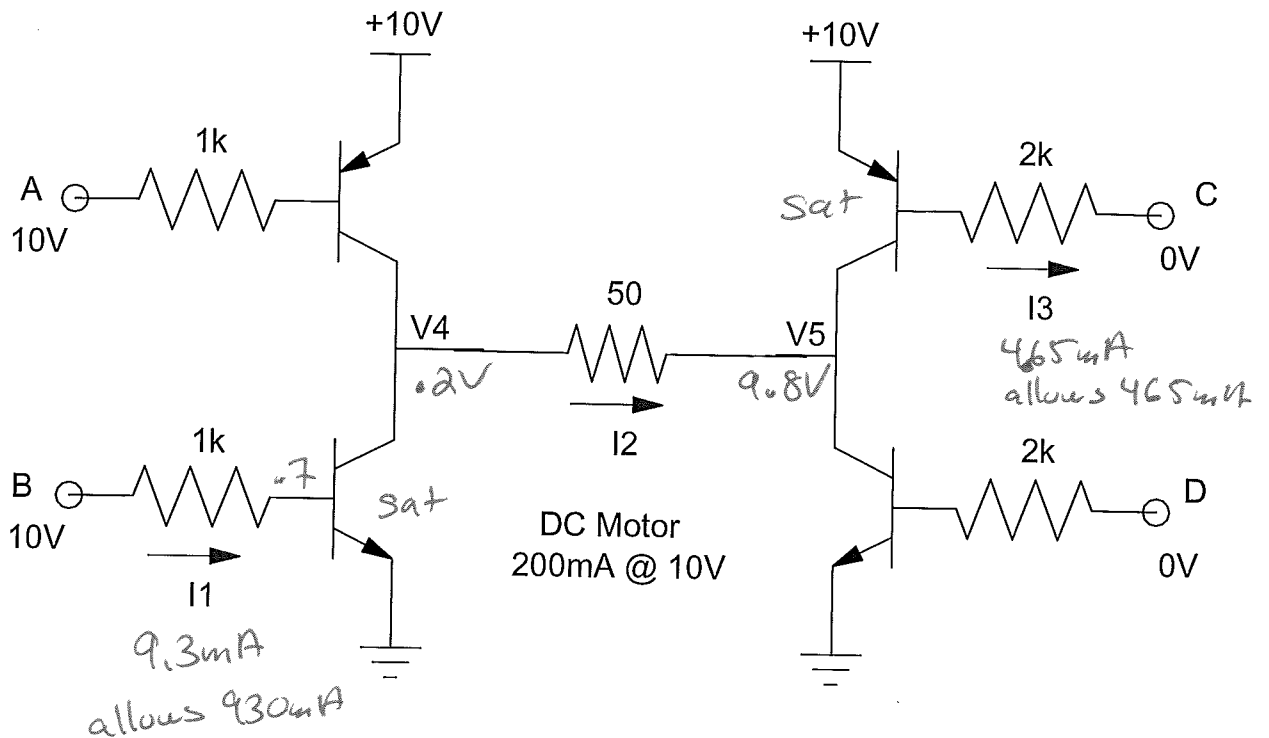




3) The following H-bridge is to drive a DC motor which draws 200mA @ 10V (modeled as a 50 Ohm resistor). Determine the voltages and currents assuming ideal silicon transistors with:

- $|V_{ce(sat)}| = 0.2V$
- $|V_{be}| = 0.7V$
- $\beta = 100$

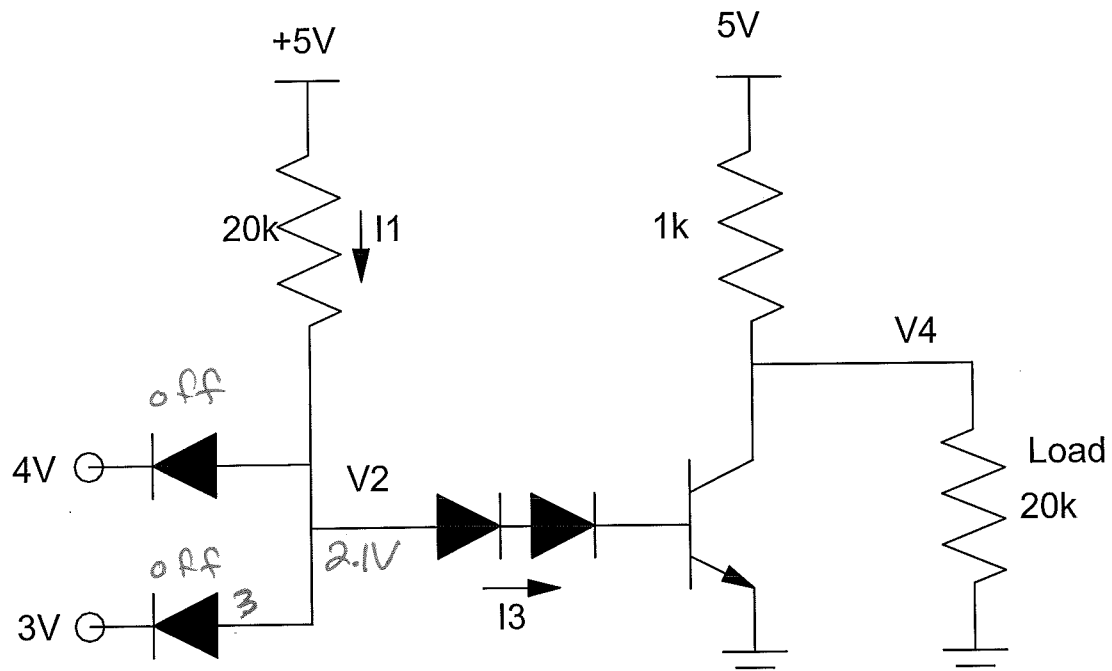
| I1    | I2     | I3     | V4  | V5   |
|-------|--------|--------|-----|------|
| 9.3mA | -192mA | 4.65mA | .2V | 9.8V |



- 4) Determine the voltages and currents for the following DTL NAND gate. Assume ideal silicon transistors with  $\beta = 100$

| I1          | V2   | I3          | V4   |
|-------------|------|-------------|------|
| 145 $\mu$ A | 2.1V | 145 $\mu$ A | 0.2V |

saturated



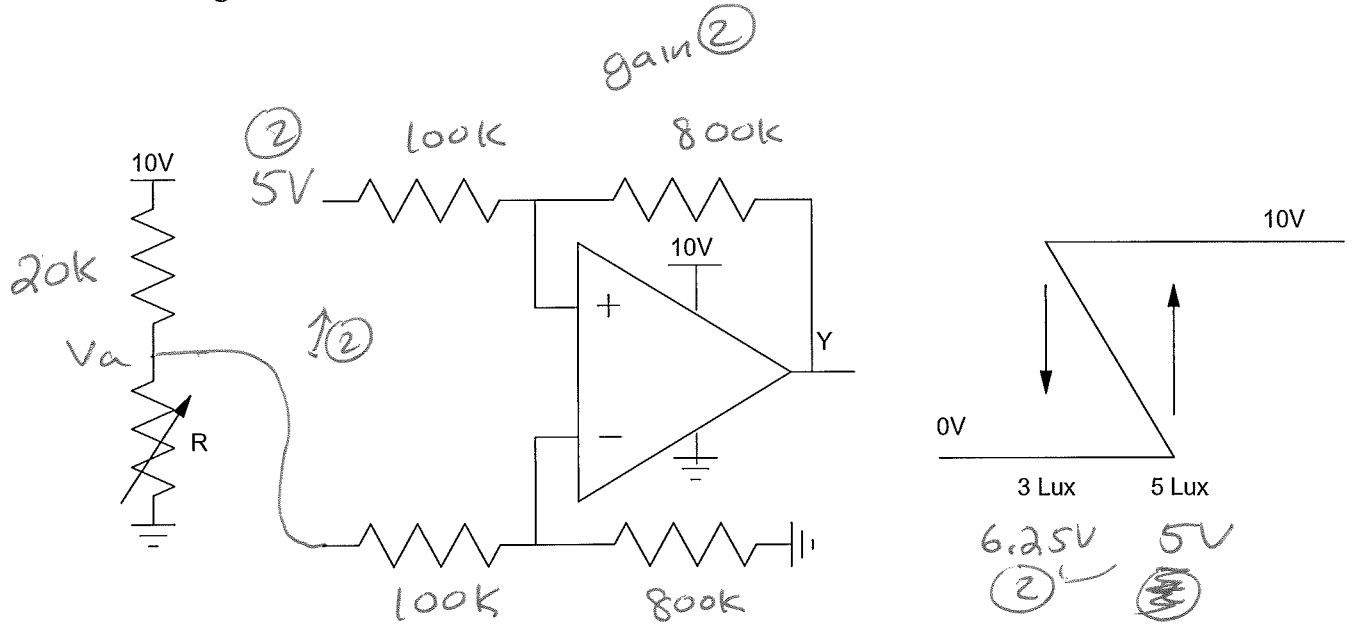
allows 14.5  $\mu$ A  
max = 5  $\mu$ A  
 $\therefore$  saturated

5) Schmitt Trigger: A light sensor has the following light - resistance relationship

$$R = \frac{100,000}{Lux}$$

Design a circuit which outputs

- 10V when the light level is more than 5 Lux
- 0V when the light level is less than 3 Lux
- No change between 3 Lux and 5 Lux



$$5 \text{ Lux} = 20k\Omega \quad 3 \text{ Lux} = 33.3k\Omega$$

$$V_a = 5V$$

$$V_a = 6.25V$$

$$\text{gain} = \frac{10V}{6.25 - 5} = 8$$

Bonus! Energy Return is how much energy you get from an investment of one unit of energy. For example, coal has an energy return of 80: you get 80 kWh of energy for every 1kWh of energy you put into mining and burning coal. (Source: Wikipedia)

Match the energy source with its energy return: (1.3, 3.0, 5.0 18.0)

| Coal | Corn Ethanol | Tar Sands | Shale Oil | Wind Energy |
|------|--------------|-----------|-----------|-------------|
| 80   | 1.3          | 3.0       | 5.0       | 18.0        |

